

SILICON RECTIFIER

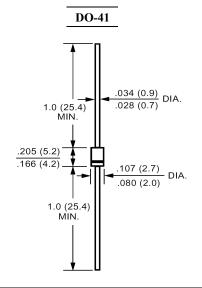
东钜兴电子科技有限公司

FEATURES

- \cdot Low forward voltage drop
- · High current capability
- · High capability
- · High surge current capability
- \cdot Exceeds environmental standards of MIL-S-19500/228

MECHANICAL DATA

Case: Molded plastic, DO-41 Epoxy: UL 94V-O rate flame retardant Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed Polarity: Color band denotes cathode end Mounting position: Any Weight: 0.012ounce, 0.33gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25 ambient temperature unless otherwise specified. Single phase, half wave, $60H_Z$, resistive or inductive load. For capacitive load, derate current by 20%.

	Symbols	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current	Т	1.0							Amp
.375"(9.5mm) Lead Length at T _A =75	I _(AV)								
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I _{FSM} 30							Amp	
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage	VF	1.1							Volts
at 1.0A DC and 25	۰F								voits
Maximum Full Load Reverse Current		30							uAmp
Full Cycle Average at 75 Ambient	30							uAmp	
Maximum Reverse Current at T _A =25	I _R	5.0 500							uAmp
at Rated DC Blocking Voltage T _A =100	IR								
Typical Junction Capacitance (Note 1)	CJ	15							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	50							/W
Operating Junction Temperature Range	TJ	-55 to +125							
Storage Temperature Range	Tstg	-55 to +125							

NOTES:

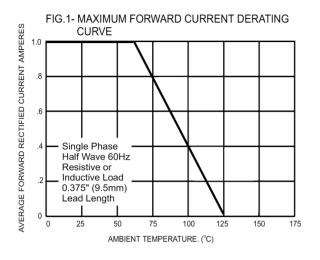
1- Measured at 1 $\ensuremath{\text{MH}_{Z}}$ and applied reverse voltage of 4.0 VDC.

2- Thermal Resistance Junction to Ambient 0.375"(9.5mm) lead length P.C.B. Mounted.



1N4001 THRU 1N4007 SILICON RECTIFIER

RATINGS AND CHARACTERISTIC CURVES





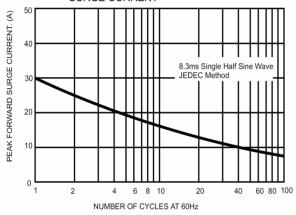
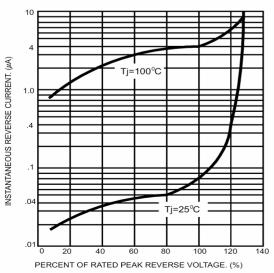


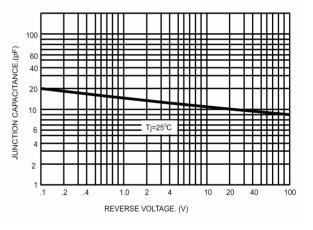
FIG.5- TYPICAL REVERSE CHARACTERISTICS



20 INSTANTANEOUS FORWARD CURRENT. (A) 10 2 1.0 .2 .1 Tj=25°C Pulse Width=300µs 1% Duty Cycle .04 .02 .01 .8 1.0 1.2 1.4 1.5 .6 FORWARD VOLTAGE. (V)

FIG.2- TYPICAL FORWARD CHARACTERISTICS

FIG.4- TYPICAL JUNCTION CAPACITANCE





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